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N-Channel 55 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}(\Omega)$ $I_{D}(A)^{d}$ $Q_{g}(\Omega)$					
55	0.0043 at V_{GS} = 10 V	100	79			
	0.0054 at V _{GS} = 4.5 V	80	19			

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Power Supply
 - Secondary Synchronous Rectification
- DC/DC Converter

TO-220 Pin Configuration	D
GDS	S N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unless otl	herwise noted)			
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	V _{DS}	55	V		
Gate-Source Voltage	V _{GS}	± 20	- V		
Continuous Drain Current ($T_1 = 150 \text{ °C}$)	T _C = 25 °C	I _D	100 ^d		
Continuous Drain Current (1j = 150°C)	T _C = 70 °C	d'	80 ^d	Α	
Pulsed Drain Current	I _{DM}	350	~		
Avalanche Current	I _{AS}	50			
Single Avalanche Energy ^a L = 0.1 mH		E _{AS}	170	mJ	
	T _C = 25 °C	P	125 ^b	10/	
Maximum Power Dissipation ^a	T _A = 25 °C ^c	– P _D –	3.0	W	
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	- 55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter Symbol Limit Ur						
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	40	°C/W			
Junction-to-Case (Drain)	R _{thJC}	1	C/VV			

Notes:

a. Duty cycle ≤ 1 %.

b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR-4 material).

d. Package limited.

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	•		•			
Drain-Source Breakdown Voltage	V _{DS}	$V_{DS} = 0 V, I_{D} = 250 \mu A$	55			V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1		4	v
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 250	nA
		$V_{DS} = 55 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μA
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 55 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 \text{ °C}$			50	
		$V_{DS} = 55 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 150 ^{\circ}\text{C}$			250	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 10$ V, $V_{GS} = 10$ V	50			А
	_	V _{GS} = 10 V, I _D = 22 A		0.0043	0.0048	0
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		0.0054	0.0060	Ω
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		159		S
Dynamic ^b						
Input Capacitance	C _{iss}			3286		pF
Output Capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = 20 V, f = 1 MHz		705		
Reverse Transfer Capacitance	C _{rss}			283		
Total Gate Charge ^c	Qg			87	131	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		15.3		nC
Gate-Drain Charge ^c	Q _{gd}			12.2		
Gate Resistance	Rg	f = 1 MHz	0.5	2.7	5.4	Ω
Turn-On Delay Time ^c	t _{d(on)}			11	20	
Rise Time ^c	t _r	V_{DD} = 20 V, R_L = 2 Ω		7	14	
Turn-Off Delay Time ^c	t _{d(off)}	${ m I}_{ m D}\cong$ 10 A, ${ m V}_{ m GEN}$ = 10 V, ${ m R}_{ m g}$ = 1 Ω		45	68	- ns
Fall Time ^c	t _f			7	14	
Drain-Source Body Diode Ratings an	nd Characteris	stics T _C = 25 °C ^b				
Continuous Current	ا _S				100	^
Pulsed Current	I _{SM}				350	A
Forward Voltage ^a	V _{SD}	I _F = 10 A, V _{GS} = 0 V		0.72	1.2	V
Reverse Recovery Time	t _{rr}			42	63	ns
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 10 A, dl/dt = 100 A/µs		2.5	3.8	А
Reverse Recovery Charge	Q _{rr}			52	78	nC

Notes:

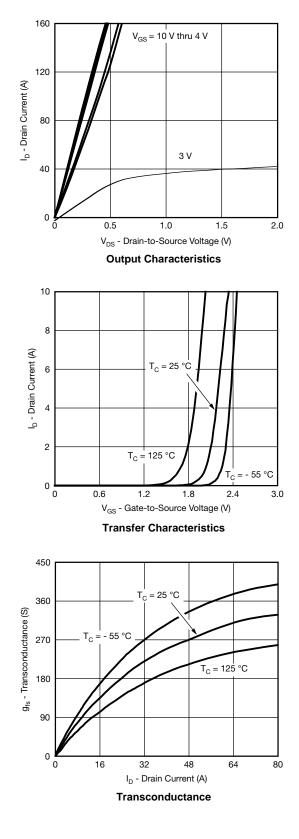
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

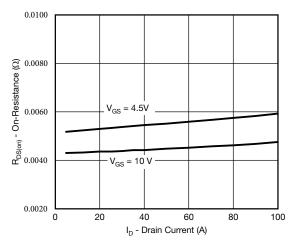
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

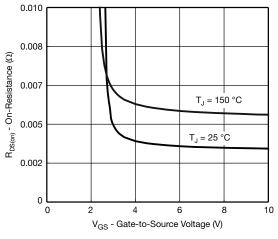


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

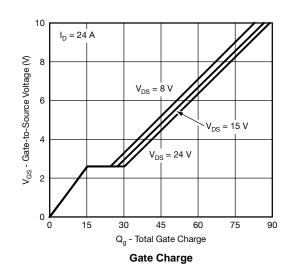




On-Resistance vs. Drain Current

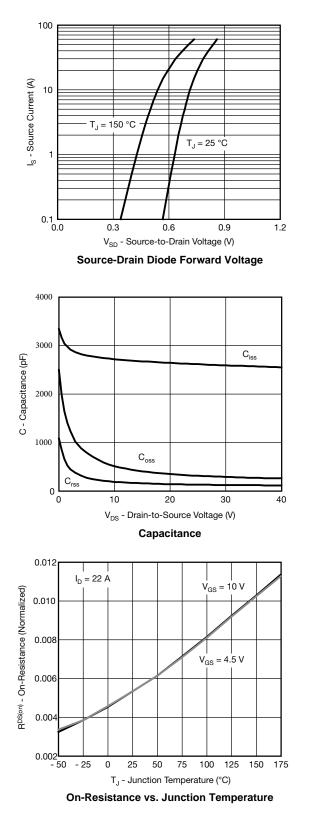


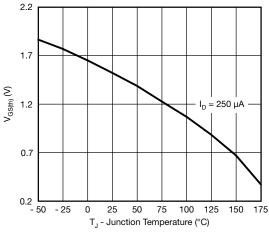




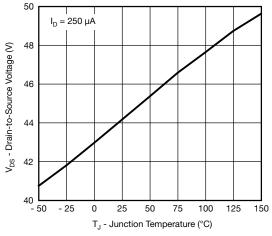


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

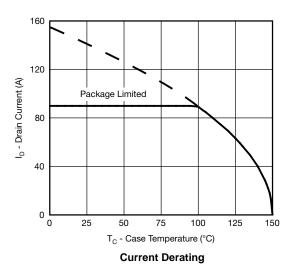




Threshold Voltage

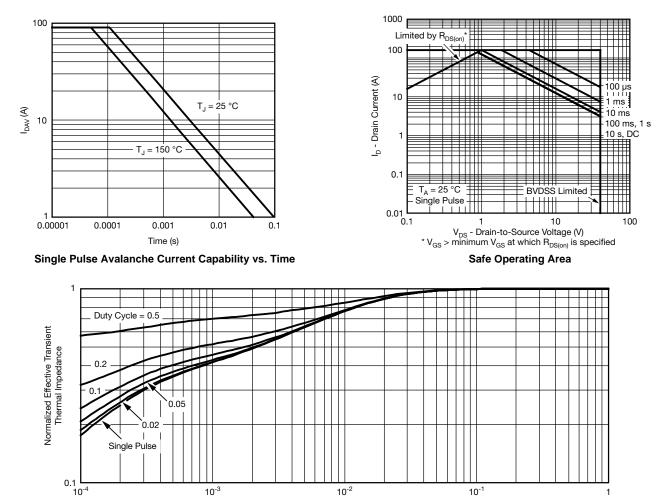


Drain Source Breakdown vs. Junction Temperature





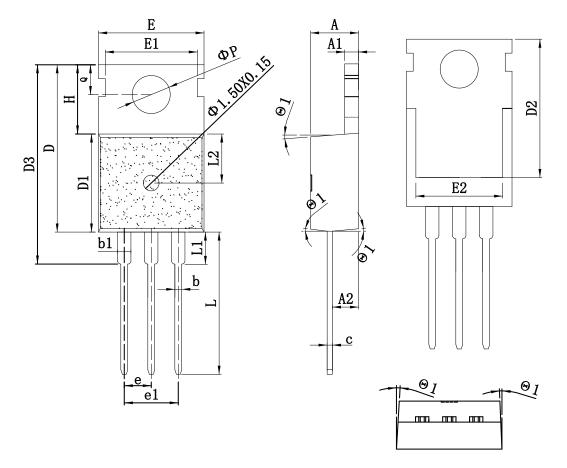




Square Wave Pulse Duration (s)
Normalized Thermal Transient Impedance, Junction-to-Case



TO-220_3L-A PACKAGE OUTLINE

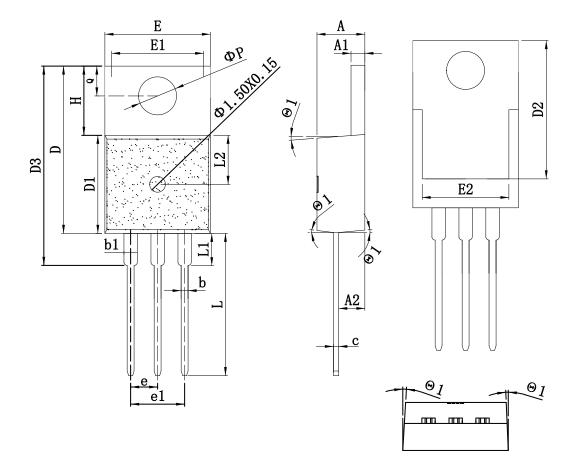


COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMDOL	SYMBOL mm			SYMBOL	mm			
SIMBOL	MIN	TYP	MAX	SIMBOL	MIN	TYP	MAX	
А	4.15	4.50	4.80	E1	8.25	8.70	9.15	
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80	
A2	2.10	2.40	2.65	e	2.38	2.54	2.74	
b	0.65	0.80	1.00	e1	5.08REF			
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90	
с	0.35	0.50	0.65	L	12.75	13.28	13.70	
D	14.25	15.75	16.15	L1	-	-	3.50	
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00	
D2	12.30	13.10	13.85	φP	3.40	3.65	3.85	
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00	
Е	8.68	10.02	11.00	θ	2°	-	7°	



TO-220_3L-B PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	mm			SYMBOL	mm			
SIMBOL	MIN	TYP	MAX	SIMBOL	MIN	TYP	MAX	
А	4.15	4.50	4.80	E1	8.25	8.70	9.15	
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80	
A2	2.10	2.40	2.65	e	2.38	2.54	2.74	
b	0.65	0.80	1.00	e1	5.08REF			
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90	
с	0.35	0.50	0.65	L	12.75	13.28	13.70	
D	14.25	15.75	16.15	L1	-	-	3.50	
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00	
D2	12.30	13.10	13.85	φP	3.40	3.65	3.85	
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00	
Е	8.68	10.02	11.00	θ	2°	-	7°	



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